# **High Voltage Transistor**

# **PNP Silicon**

## Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

## MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Collector – Emitter Voltage	tter Voltage V <sub>CEO</sub> –150			
Collector-Base Voltage	V <sub>CBO</sub>	-160	Vdc	
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	Vdc	
Collector Current – Continuous	Ι <sub>C</sub>	-500	mAdc	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 2) $T_A = 25^{\circ}C$ Derate Above 25°C	P <sub>D</sub>	400 3.2	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	312	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

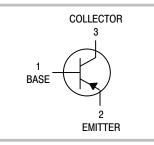
1. FR-5 @ 100 mm<sup>2</sup>, 0.5 oz. copper traces, still air.

2. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.



# **ON Semiconductor®**

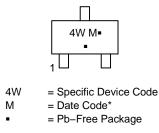
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SC-70 (SOT-323) CASE 419 STYLE 3

## MARKING DIAGRAM



(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBT5401WT1G,	SC–70	3000 / Tape &
NSVMMBT5401WT1G	(Pb–Free)	Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = $25^{\circ}$ C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage $(I_C = -1.0 \text{ mAdc}, I_B = 0)$	V <sub>(BR)CEO</sub>	-150	-	Vdc
Collector-Base Breakdown Voltage $(I_C = -100 \ \mu Adc, I_E = 0)$	V <sub>(BR)CBO</sub>	-160	-	Vdc
Emitter–Base Breakdown Voltage $(I_E = -10 \ \mu Adc, I_C = 0)$	V <sub>(BR)EBO</sub>	-5.0	-	Vdc
Collector–Base Cutoff Current $(V_{CB} = -120 \text{ Vdc}, I_E = 0)$ $(V_{CB} = -120 \text{ Vdc}, I_E = 0, T_A = 100^{\circ}\text{C})$	Ісво	-	-50 -50	nAdc μAdc

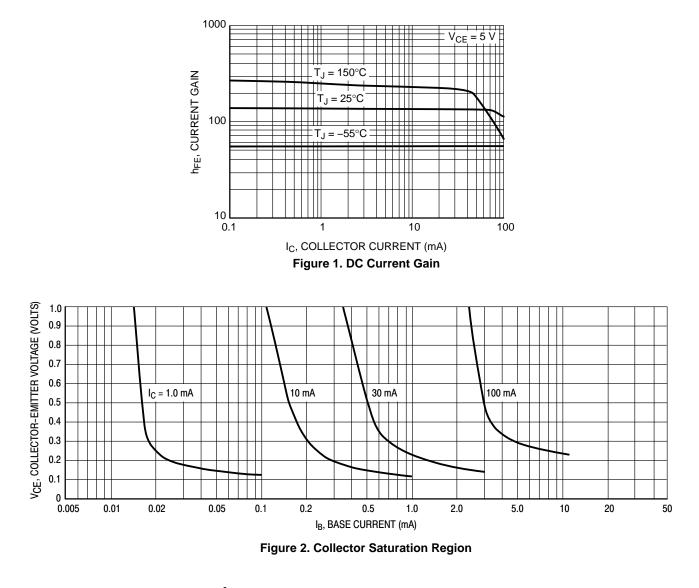
#### **ON CHARACTERISTICS**

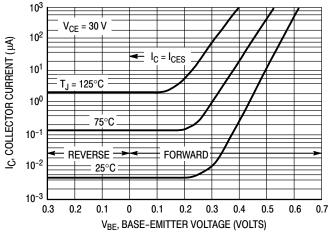
$ \begin{array}{l} \mbox{DC Current Gain} \\ (I_C = -1.0 \mbox{ mAdc}, V_{CE} = -5.0 \mbox{ Vdc}) \\ (I_C = -10 \mbox{ mAdc}, V_{CE} = -5.0 \mbox{ Vdc}) \\ (I_C = -50 \mbox{ mAdc}, V_{CE} = -5.0 \mbox{ Vdc}) \end{array} $	h <sub>FE</sub>	50 60 50	_ 240 _	-
Collector – Emitter Saturation Voltage $(I_C = -10 \text{ mAdc}, I_B = -1.0 \text{ mAdc})$ $(I_C = -50 \text{ mAdc}, I_B = -5.0 \text{ mAdc})$	V <sub>CE(sat)</sub>		-0.2 -0.5	Vdc
Base – Emitter Saturation Voltage $(I_C = -10 \text{ mAdc}, I_B = -1.0 \text{ mAdc})$ $(I_C = -50 \text{ mAdc}, I_B = -5.0 \text{ mAdc})$	V <sub>BE(sat)</sub>	- -	-1.0 -1.0	Vdc

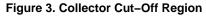
#### SMALL-SIGNAL CHARACTERISTICS

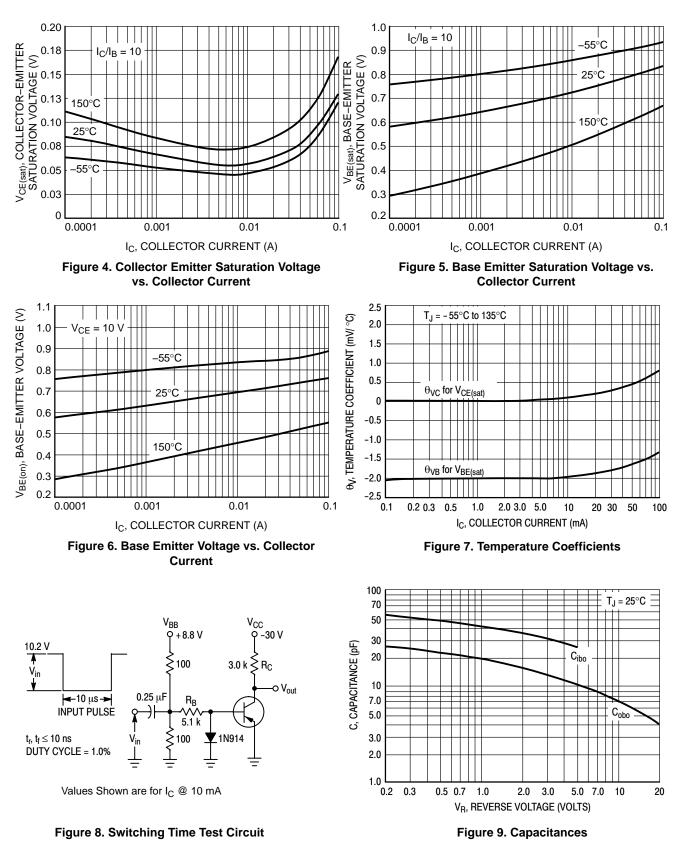
Current-Gain — Bandwidth Product ( $I_C = -10 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}, f = 100 \text{ MHz}$ )	f <sub>T</sub>	100	300	MHz
Output Capacitance (V <sub>CB</sub> = -10 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>obo</sub>	-	6.0	pF
Small Signal Current Gain ( $I_C = -1.0 \text{ mAdc}$ , $V_{CE} = -10 \text{ Vdc}$ , f = 1.0 kHz)	h <sub>fe</sub>	40	200	-
Noise Figure (I <sub>C</sub> = -200 $\mu$ Adc, V <sub>CE</sub> = -5.0 Vdc, R <sub>S</sub> = 10 $\Omega$ , f = 1.0 kHz)	NF	-	8.0	dB

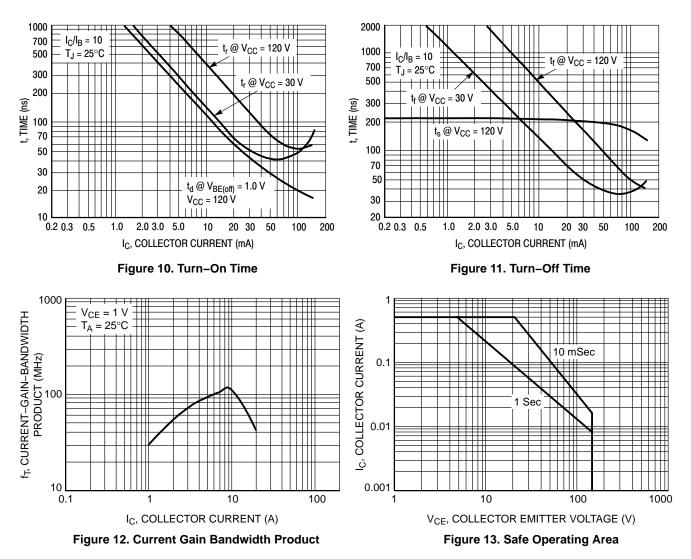
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.





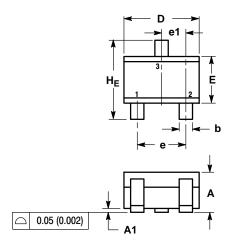


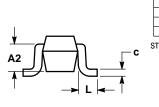




#### PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04 ISSUE N





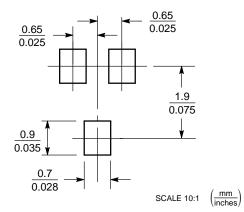
NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.70 REF			0.028 REF		
b	0.30	0.35	0.40	0.012	0.014	0.016
С	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
Е	1.15	1.24	1.35	0.045	0.049	0.053
е	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC 0.026 BSC			;		
L	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095



2. EMITTER 3. COLLECTOR

#### SOLDERING FOOTPRINT\*



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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